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High-Temperature Fractional Quantum Hall States

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We show that a suitable combination of geometric frustration, ferromagnetism, and spin-orbit interactions can give rise to nearly flatbands with a large band gap and nonzero Chern number. Partial filling of the flatband can give rise to fractional quantum Hall states at high temperatures (maybe even room temperature). While the identification of material candidates with suitable parameters remains open, our work indicates intriguing directions for exploration and synthesis.

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Landau symmetry breaking [1,2] has been the standard theoretical concept in the classification of phases and transitions between them. However, this theory turned out to be insufficient when the fractional quantum Hall (FQH) state [3,4] was discovered. These highly entangled quantum states are not distinguished by symmetries but characterized by new topological quantum numbers such as robust ground state degeneracy [5,6] and robust non-Abelian Berry’s phases [7] of the ground states [8]. The new kind of order revealed in these topological quantum numbers is named topological order [8,9]. Recently, it was realized that topological order can be interpreted as patterns of long-range quantum entanglement [10–12]. This entanglement has important applications for topological quantum computation: the robust ground state degeneracy can be used as quantum memory [13]. Fractional defects from the entangled states which carry fractional charges [4] and fractional statistics [14–16] (or non-Abelian statistics [17,18]) can be used to perform fault tolerant quantum computation [19,20].

Presently, highly entangled gapped phases in FQH systems [3,4] are only realized at very low temperatures. Here we present a proposal to realize these states at high temperatures (even room temperature). The ideal is to combine spin-orbit coupling, ferromagnetism, and geometric frustration. Both spin-orbit coupling and ferromagnetism can have high energy scales and can appear at room temperature. In some cases, combining them leads to energy bands with nonzero Chern numbers and filling such an energy band will give rise to integer quantum Hall states. Further, in geometrically frustrated systems—lattices on which hopping is frustrated—some of these topologically nontrivial energy bands can be very flat [21,22]. These would mimic Landau levels in free space. When such a flatband with a nonzero Chern number is partially filled (such as 1/3 or 1/2 filled), FQH states can appear. Here we study a simple example of this idea on the geometrically frustrated kagome lattice.

Several aspects of these ideas have been active in recent research. Spin-orbit coupling can lead to a topological insulator in various geometrically frustrated systems [23–26], and noncollinear magnetic order can lead to integer quantum Hall states [24,27]. Alternatively, interactions in geometrically frustrated systems can break time-reversal symmetry [28–36] which again can give rise to integer quantum Hall states. Here we show that an extension of these ideas may set the stage for FQH states and other highly entangled states with fractional statistics and fractional charges—possibly even at room temperature.

Nearby flatband; nonzero Chern number.—We consider nearest and next-nearest-neighbor hopping on a kagome lattice with spin-orbit interactions in the Hamiltonian

$$H = -t_1 \sum_{\langle ij \rangle \sigma} c_{i\sigma}^\dagger c_{j\sigma} + i \lambda_1 \sum_{\langle ij \rangle \alpha \beta} (\mathbf{E}_{ij} \times \mathbf{R}_{ij}) \cdot \mathbf{\sigma}_{\alpha \beta} c_{i\alpha}^\dagger c_{j\beta}$$

$$- t_2 \sum_{\langle ii' \rangle \sigma} c_{i\sigma}^\dagger c_{i'\sigma} + i \lambda_2 \sum_{\langle ii' \rangle \alpha \beta} (\mathbf{E}_{ii'} \times \mathbf{R}_{ii'}) \cdot \mathbf{\sigma}_{\alpha \beta} c_{i\alpha}^\dagger c_{i'\beta},$$

(1)

where $c_{i\sigma}^\dagger$ creates an electron with spin $\sigma$ on site $\mathbf{r}_i$ (see Fig. 1). Here $\langle ij \rangle$ denotes nearest neighbors and $\langle ii' \rangle$ next-nearest neighbors. The second and fourth terms are time-reversal invariant and describe spin-orbit interactions. $\mathbf{R}_{ij}$ is the distance vector between sites $i$ and $j$ and $\mathbf{E}_{ij}$ the electric field from neighboring ions experienced along $\mathbf{R}_{ij}$.

To obtain FQH states we need to break time-reversal symmetry. This is likely to happen spontaneously from exchange effects in the flatband that cause ferromagnetism [28–30]. Alternatively, one can apply an external magnetic field or couple the system to a ferromagnet. In the extreme limit the electron spins are totally polarized within the partially filled band—the case we examine here. Hence, we consider spin-orbit coupling that also conserves $S_z$; i.e., the electric field on each site is in the 2D plane. First studying just nearest-neighbor hopping ($t_2 = \lambda_2 = 0$), in momentum-space Eq. (1) is
The Chern number is defined as \[ c = \frac{1}{2\pi} \int_{\mathbb{R}^2} d^2 k F_{12}(k), \] (3)

where \( F_{12}(k) \) is the associated field strength given by \( F_{12}(k) = \frac{1}{\hbar} A_2(k) - \frac{\alpha}{\hbar} A_1(k) \) with the Berry connection \( A_\mu(k) = -i (n_k | \frac{\partial}{\partial k} | n_k) \). In the above \( |n_k\) is a normalized wave function of the respective band.

Focusing on the lowest band which has a nonzero Chern number, we look for where this band is very flat compared to the band gap and the energy scale of interactions. We denote \( W \) as the maximum bandwidth of the lowest band, \( \Delta_{12} \) as the minimum band gap between the two lowest bands, and \( U \) as the strength of electron-electron interactions. When \( U \gg W \), interaction effects dominate kinetic energy and partially filling the flatband would favor the Laughlin state \cite{4}. Since band mixing could destroy band flatness, ideally \( \Delta_{12} \gg U \). Hence we aim to maximize the ratio \( \Delta_{12}/W \) in order to obtain FQH states. As the middle band has zero Chern number, any mixing between only two of the bands would not change the Chern number of the lowest band. If the lowest band remains flat even with mixing then \( \Delta_{13} \), the minimum band gap between the lowest and highest bands (and consequently the ratio \( \Delta_{13}/W \)) is also of interest.

We find that \( W \gg \Delta_{12} \) always—as the bandwidth vanishes so does the band gap between the two lower bands (topological symmetry in real space \cite{38}), see Fig. 2. Here we show the band structure for \( \lambda_1 = 1 \) where \( W = 1.3 \) and \( \Delta_{13}/W = 3.7 \). The spectrum does not have a clear separation of energy scales when interactions are on the order of \( W \), the bands will mix. This scenario is quite different from Landau levels in free space that are flat and well separated, which could be due to limitations of this simplest model.

For a more realistic scenario we include second-nearest-neighbor hopping which adds terms in the Hamiltonian

\[
H_k = -2t_2 \begin{pmatrix}
0 & \cos(k_2 + k_3) & \cos(k_3 - k_1) \\
\cos(k_2 + k_3) & 0 & \cos(k_1 + k_2) \\
\cos(k_3 - k_1) & \cos(k_1 + k_2) & 0 \\
\end{pmatrix}
\]

\[ + i2\lambda_2 \begin{pmatrix}
0 & -\cos(k_2 + k_3) & \cos(k_3 - k_1) \\
-\cos(k_2 + k_3) & 0 & -\cos(k_1 + k_2) \\
\cos(k_3 - k_1) & -\cos(k_1 + k_2) & 0 \\
\end{pmatrix}. \] (4)

In this larger parameter space the band maxima and minima are no longer fixed at the same symmetry points. We find that the largest values of \( \Delta_{12}/W \) (and \( \Delta_{13}/W \)) occur when \( \lambda_1 \) and \( \lambda_2 \) are of the same sign—in which case the results are symmetric under changing signs of both \( \lambda \)'s in this spin polarized case. In Fig. 3, \( \Delta_{12}/W \) is plotted as a function of \( t_2 \) for three values of \( \lambda_1 = \lambda_2 \). We see that at

FIG. 1. The kagome lattice is a triangular Bravais lattice with a 3-point basis labeled \( l = 1, 2, 3; a_1 = \hat{x} \) and \( a_2 = (\hat{x} + \sqrt{3}\hat{y})/2 \) are the basis vectors. In the metallic kagome lattice \( \text{Fe}_5\text{Sn}_2 \), spin-orbit coupling arises from the electric field due to the Sn ion at the center of the hexagon.
negative values of $t_2$ a lower spin-orbit coupling is needed, while for positive values of $t_2$ higher values of spin-orbit coupling would maximize the band gap to bandwidth ratio.

We present two examples where $\Delta_{12}/W$ and $\Delta_{13}/W$ reach high values at $t_2 = -0.3$. In case 1, setting $t_2 = -0.3$, $\lambda_1 = 0.28$, and $\lambda_2 = 0.2$, we obtain a very flat lowest band separated from the two higher bands by a large gap (see Fig. 4). The values of $\Delta_{12}/W$ and $\Delta_{13}/W$ are 52 and 99, respectively. In another example, all three bands are fairly flat (particularly the lowest one) and mutually well separated. The parameters used are $t_2 = -0.3$, $\lambda_1 = 0.6$, and $\lambda_2 = 0$. In case 2, we obtain $\Delta_{12}/W = 8.7$ and $\Delta_{13}/W = 24$, respectively (see Fig. 5).

Calculating the Chern number $\gamma$ of the lowest flatband in these two cases, we find it is 1. This is expected as slowly turning off $t_2$ and $\lambda_2$ does not close the band gap—and we have previously seen that in the absence of next-nearest-neighbor hopping, the lowest band always has unit Chern number. When $\Delta \gg U \gg W$ is satisfied, partial filling of this flatband would favor the FQH state.

The distribution of the field strength $F_{12}(k)$ in the Brillouin zone is plotted in Fig. 6. We observe there are no singularities or very sharp features but $F_{12}(k)$ varies fairly smoothly especially in the first case with the flatter band. The presence of singularities—e.g., localized at the Dirac point—would have signaled a new (and much larger) length scale in the system. In our case, both the magnetic length scale (arising from spin-orbit interactions) and the variation of field strength $F_{12}(k)$ are on the order of the lattice constant $a$.

Thus, the interaction energy scale is generated from the lattice constant $a$: $U \sim \varepsilon^2/ea$ where $\varepsilon$ is the dielectric constant. For a 1/3 filled flatband, analogous to results from FQH states in semiconductor-based systems [39], the gap for this $\nu = 1/3$ state is roughly $0.09\varepsilon^2/ea = 500$ K. (We choose $\varepsilon = 3$ and $a = 10$ Å; $a$ is defined as the square root of the unit cell area.) As the interaction energy scale is a hundred times larger than in semiconductors, we may see the FQH effect at room temperature. As band gaps $\Delta_{12}$ and $\Delta_{13}$ are easily much higher than room temperature, a fully filled band could give the integer quantum Hall state at unusually high temperatures too.

Materials realization.—We see that a suitable combination of geometric frustration, ferromagnetism, and spin-orbit interactions can give rise to nearly flatbands with a large band gap and nonzero Chern number. The ferromag-
netism can arise from an external magnetic field, a ferromagnetic substrate for a thin film sample, and/or exchange effects. If the flatband is close to the Fermi energy, partial filling of the flatband can be controlled by doping and give rise to FQH states at high temperatures.

The choice of parameters in our calculations is based on known values of spin-orbit coupling. For example, in Herbertsmithite (a common copper-based 2D kagome lattice) the spin-orbit interaction is 8% of the kinetic energy [40]. Other compounds with 4$d$ or 5$d$ orbitals (instead of 3$d$ as in Cu) may experience a larger spin-orbit interaction. For instance, the strength of spin-orbit coupling in iridium-based kagome compounds can be on the order of magnitude of the kinetic energy; hence, the substitution with 4$d$ or 5$d$ atoms in metallic kagome lattices could result in hopping parameters similar to the ones used in our work. Alternatively, making thin films of frustrated lattices with 4$d$ or 5$d$ atoms may lead to a flatband with strong spin-orbit coupling, where exchange effects in this flatband could cause ferromagnetism.

Most existing kagome compounds are Cu-based insulators. Some 2D kagome lattices show metallic behavior, for instance Fe$_2$Sb$_2$ [41,42] which shows ferromagnetism along the c axis above 60 K and in the kagome plane below 60 K. Also, as spin-orbit interactions can be simulated in cold atom systems [43,44], it is possible to realize our hopping model in such systems. This would provide a method to obtain FQH states in cold atom systems.

In short, flatbands with nonzero Chern number arise in the examples we have given and in other geometrically frustrated systems with suitable levels of spin-orbit interaction. By partially filling these bands, e.g., via doping, one can expect the emergence of FQH states at high temperatures. While the identification of exact material candidates remains open, our work indicates intriguing directions for synthesis and development.

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Note added.—Recently, we learned that Neupert et al. [45] also discussed the possibility of the FQH effect in interacting two-band lattice systems, while Sun et al. [46] found flatbands with nonzero Chern numbers on various lattices (including the kagome lattice) after including some complex hopping.

References